



Revision 1.01

GAIN CHIPS AR coated Fabry-Perot Laser





General Product Information

Product	Application
tunable 860 nm Fabry-Perot Laser	Cs Spectroscopy
for use in an External Cavity Diode Laser (ECDL)	Atomic Clocks
sealed SOT Housing	
Monitor Diode	



Absolute Maximum Ratings

Parameter	Symbol	Unit	min	typ	max
Storage Temperature	Ts	°C	-40		85
Operational Temperature at Case	T_{C}	°C	-20		50
Forward Current	I _F	mA			200
Reverse Voltage	V_R	V			0
Output Power (extracavity)	P _{opt}	mW			100

Measurement Conditions / Comments

Stess in excess of the Absolute Maximum Ratings can cause permanent damage to the device.

Recommended Operational Conditions

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	T _C	°C	15		40
Forward Current	I _F	mA			180

Measurement Conditions / Comments

Characteristics at T_{LD}= at 25 °C at BOL, with external cavity under recommended working condition

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	λ_{C}	nm		860	
Tuning Range	$\Delta \lambda_{\text{tun}}$	nm	830		880
Output Power	P _{opt}	mW		80	
Polarization				TE	
Spatial Mode (transversal)				TEM ₀₀	
Monitor Detector Responsivity	I_{mon} / P_{ASE}	μA/mW	1		40

Measurement Conditions / Comments

The actual achieved wavelength and power are strongly influenced by the external cavity. eyP gives no guarantee on these parameters.

E field parallel to Pin 2 - Pin 3 - plane Fundamental Mode $U_{RMD} = 5 \text{ V}$



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Chip Parameter

Parameter	Symbol	Unit	min	typ	max
Cavity Length	L	μm		1500	
Reflectivity at Front Facet	R_{ff}			3·10 ⁻⁴	1·10 ⁻³

Measurement Conditions / Comments

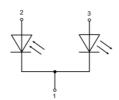
Package Dimensions

Parameter	Symbol	Unit	min	typ	max
Height of Emission Plane	h	mm	3.50	3.65	3.70
Excentricity of Emission Center	R	mm			0.12
Pin Length	L_{PIN}	mm		14	

Measurement Conditions / Comments
reference plane: top side of TO header
reference: center of outer diameter of header

Package Pinout

- 1 Laser Diode Cathode, Monitor Diode Cathode, Case
- 2 Photo Diode Anode
- 3 Laser Diode Anode





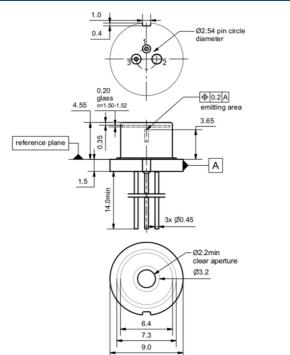


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Package Drawings





AIZ-16-0421-1517

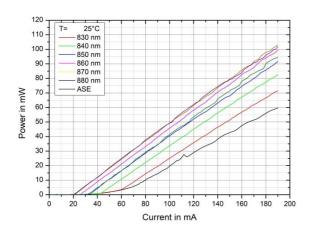


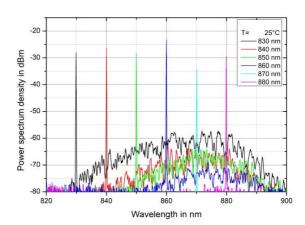
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Typical Measurement Results

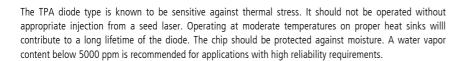




Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.



The laser emission from this diode is close to the invisible infrared region of the electromagnetic spectrum. Avoid direct and/or indirect exposure to the free running beam. Collimating the free running beam with optics as common in optical instruments will increase threat to the human eye.

Each laser diode will come with an individual test protocol verifying the parameters given in this document.







INVISIBLE LASER RADIATION
AVOID EYE OR SKIN EXPOSURE
TO DIRECT OR SCATTERED RADIATION
CLASS 4 LASER PRODUCT
WAVELENGTH 860 nm
MAX. OUTPUT POWER 100 mW





